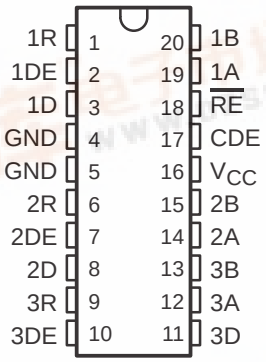
SN75ALS171, SN75ALS171A
TRIPLE DIFFERENTIAL BUS TRANSCEIVERS

SLLS056D – AUGUST 1987 – REVISED SEPTEMBER 1995

- Three Bidirectional Transceivers
- Driver Meets or Exceeds the Requirements of ANSI EIA/TIA-422-B and RS-485 and ITU Recommendation V.11
- Two Skew Limits Available
- Designed to Operate Up to 20 Million Data Transfers per Second (FAST-20 SCSI)
- High-Speed Advanced Low-Power Schottky Circuitry
- Low Pulse Skew . . . 5 ns Max
- Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments
- Features Independent Driver Enables and Combined Receiver Enables
- Wide Positive and Negative Input/Output Bus Voltages Ranges
- Driver Output Capacity . . . ±60 mA
- Thermal Shutdown Protection
- Driver Positive- and Negative-Current Limiting
- Receiver Input Impedances . . . 12 kΩ Min
- Receiver Input Sensitivity . . . ±300 mV Max
- Receiver Input Hysteresis . . . 60 mV Typ
- Operates From a Single 5-V Supply
- Glitch-Free Power-Up and Power-Down Protection

DW OR J PACKAGE
(TOP VIEW)



description

The SN75ALS171 and the SN75ALS171A triple differential bus transceivers are monolithic integrated circuits designed for bidirectional data communication on multipoint bus transmission lines. They are designed for balanced transmission lines, and each driver meets ANSI Standards EIA/TIA-422-B and RS-485 and both the drivers and receivers meet ITU Recommendation V.11. The SN75ALS171A is designed for FAST-20 SCSI and can transmit or receive data pulses as short as 30 ns with a maximum skew of 5 ns.

The SN75ALS171 and the SN75ALS171A operate from a single 5-V power supply. The drivers and receivers have individual active-high and active-low enables, respectively, which can be externally connected together to function as a direction control. The driver differential output and the receiver differential input pairs are connected internally to form differential input/output (I/O) bus ports that are designed to offer minimum loading to the bus when the driver is disabled or V_{CC} is at 0 V. These ports feature wide positive and negative common-mode voltage ranges making the device suitable for party-line applications.

The SN75ALS171 and the SN75ALS171A are characterized for operation from 0°C to 70°C.

Function Tables

EACH DRIVER

INPUT D	ENABLES		OUTPUTS	
	DE	CDE	A	B
H	H	H	H	L
L	H	H	L	H
X	L	X	Z	Z
X	X	L	Z	Z

EACH RECEIVER

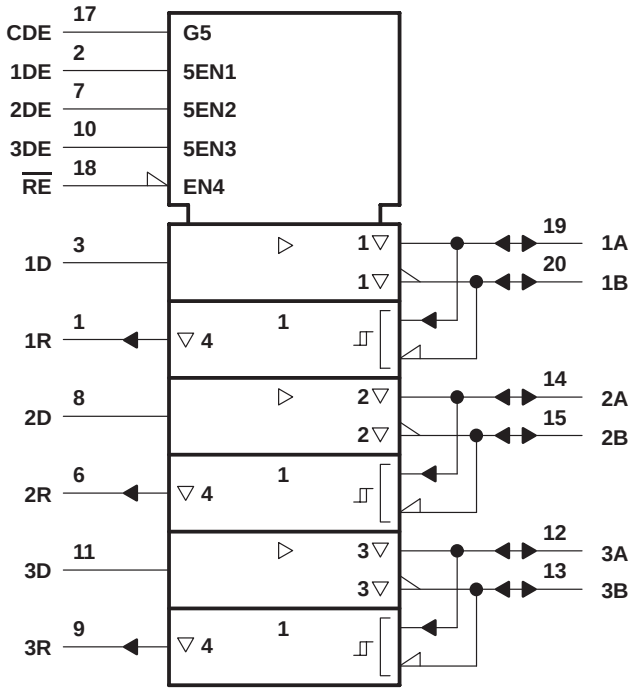
DIFFERENTIAL INPUTS A – B	ENABLE $\overline{RE}$	OUTPUT R
$V_{ID} \geq 0.3$ V	L	H
-0.3 V $< V_{ID} < 0.3$ V	L	?
$V_{ID} \leq -0.3$ V	L	L
X	H	Z
Open	L	H

H = high level, L = low level, ? = indeterminate, X = irrelevant, Z = high impedance (off)

AVAILABLE OPTIONS

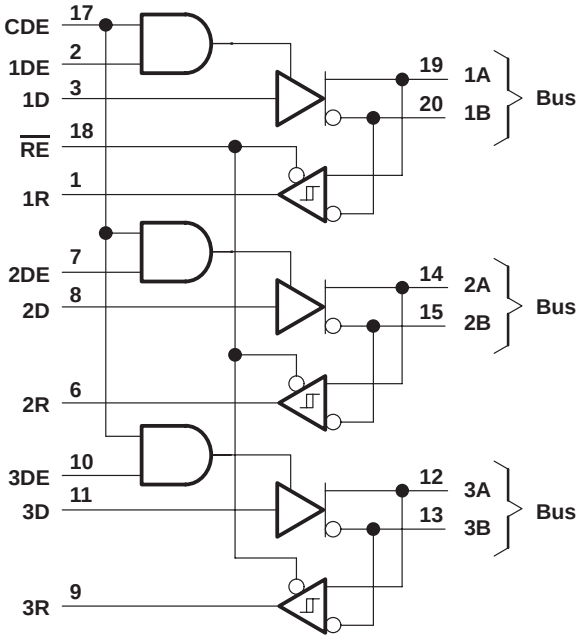
SKEW LIMIT	PART NUMBER	
10 ns	SN75ALS171DW	SN75ALS171J
5 ns	SN75ALS171ADW	

logic symbol†

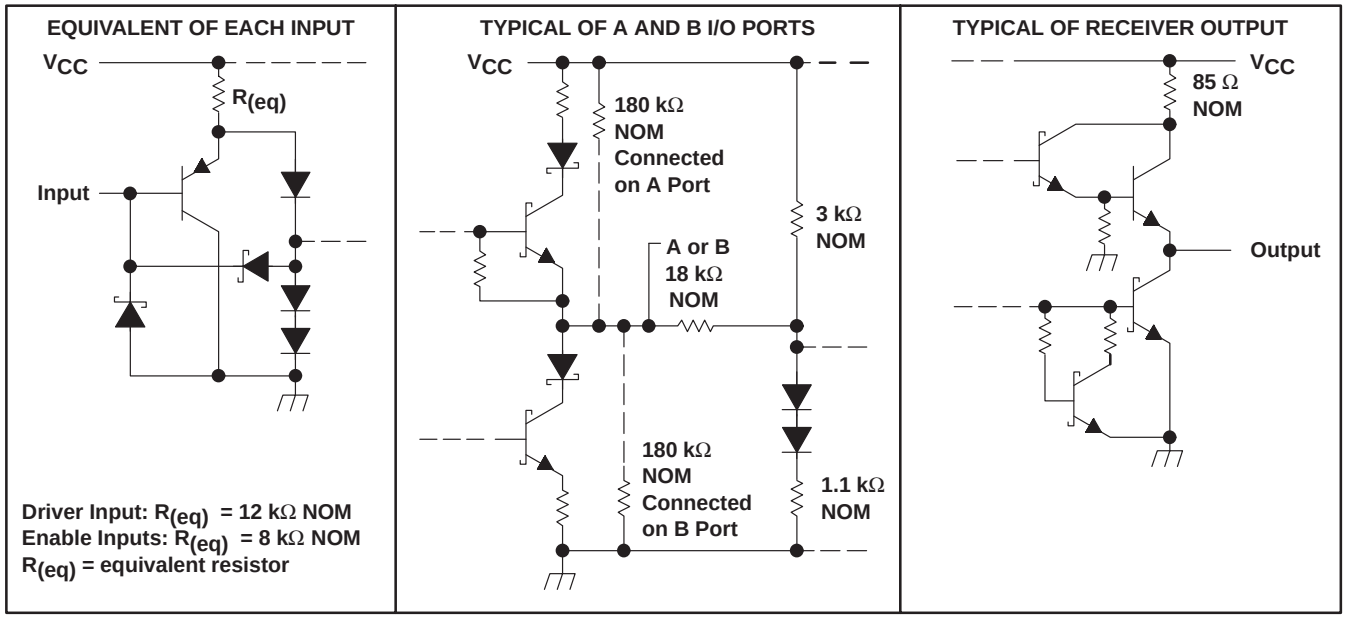


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} (see Note 1) . . . . . 7 V
Voltage range at any bus terminal . . . . . –7 V to 12 V
Enable input voltage, V_I . . . . . 7 V
Continuous total power dissipation . . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A . . . . . 0°C to 70°C
Storage temperature range, T_{stg} . . . . . –65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DW package . . . . . 260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package . . . . . 300°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential I/O bus voltage, are with respect to network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING
DW	1125 mW	9.0 mW/°C	720 mW
J	1025 mW	8.2 mW/°C	656 mW

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.75	5	5.25	V
Voltage at any bus terminal (separately or common mode), V_I or V_{IC}		–7		12	V
High-level input voltage, V_{IH}	D, CDE, DE, and $\overline{RE}$	2			V
Low-level input voltage, V_{IL}	D, CDE, DE, and $\overline{RE}$			0.8	V
Differential input voltage, V_{ID} (see Note 2)				±12	V
High-level output current, I_{OH}	Driver			–60	mA
	Receiver			–400	µA
Low-level output current, I_{OL}	Driver			60	mA
	Receiver			8	
Operating free-air temperature, T_A		0		70	°C

NOTE 2: Differential-input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.

DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		MIN	TYP‡	MAX	UNIT
V_{IK}	Input clamp voltage	I_I = –18 mA				–1.5	V
V_O	Output voltage	I_O = 0		0		6	V
V_{OH}	High-level output voltage	V_{CC} = 4.75 V, V_{IL} = 0.8 V,	V_{IH} = 2 V, I_{OH} = –55 mA	2.7			V
V_{OL}	Low-level output voltage	V_{CC} = 4.75 V, V_{IL} = 0.8 V,	V_{IH} = 2 V, I_{OL} = 55 mA			1.7	V
$\lvert V_{OD1} \rvert$	Differential output voltage	I_O = 0		1.5		6	V
$\lvert V_{OD2} \rvert$	Differential output voltage	R_L = 100 Ω,	See Figure 1	1/2 V_{OD1} or 2§	2.5	5	V
		R_L = 54 Ω,	See Figure 1	1.5	2.5	5	
V_{OD3}	Differential output voltage	V_{test} = –7 V to 12 V,	See Figure 2	1.5		5	V
$\Delta\lvert V_{OD} \rvert$	Change in magnitude of differential output voltage¶	R_L = 54 Ω or 100 Ω,	See Figure 1			±0.2	V
V_{OC}	Common-mode output voltage					3	V
						–1	
$\Delta\lvert V_{OC} \rvert$	Change in magnitude of common-mode output voltage¶					±0.2	V
I_O	Output current	Output disabled, See Note 3	V_O = 12 V			1	mA
			V_O = –7 V			–0.8	
I_{IH}	High-level enable-input current	D and DE	V_{IH} = 2.7 V			20	μA
		CDE				60	
I_{IL}	Low-level enable-input current	D and DE	V_{IL} = 0.4 V			–100	
		CDE				–900	
I_{OS}	Short-circuit output current	V_O = –6 V				–250	mA
		V_O = 0				–150	
		V_O = V_{CC}				250	
		V_O = 8 V				250	
I_{CC}	Supply current	No load	Outputs enabled		69	90	mA
			Outputs disabled		57	78	

† The power-off measurement in ANSI Standard EIA/TIA-422-B applies to disabled outputs only and is not applied to combined inputs and outputs.
‡ All typical values are at V_{CC} = 5 V and T_A = 25°C.
§ The minimum V_{OD2} with 100-W load is either 1/2 V_{OD2} or 2 V, whichever is greater.
¶ $\Delta\lvert V_{OD} \rvert$ and $\Delta\lvert V_{OC} \rvert$ are the changes in magnitude of V_{OD} and V_{OC}, respectively, that occur when the input is changed from a high level to a low level.

NOTE 3: This applies for both power on and off; refer to EIA Standard RS-485 for exact conditions. The EIA/TIA-422-B limit does not apply for a combined driver and receiver terminal.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER			TEST CONDITIONS		MIN	TYP†	MAX	UNIT
$t_{d(OD)}$	Differential output delay time	ALS171	R_L = 54 Ω, C_L = 50 pF	See Figure 3,	3		13	ns
		ALS171A			6		11	
		ALS171	$R_{L1} = R_{L3}$ = 165 Ω, C_L = 60 pF, R_{L2} = 75 Ω,	V_{TERM} = 5 V, See Figure 6	3		13	
		ALS171A			6		11	
$t_{sk(p)}$	Pulse skew‡		R_L = 54 Ω, See Figure 3	C_L = 50 pF,		1	5	ns
			$R_{L1} = R_{L3}$ = 165 Ω, C_L = 60 pF,	R_{L2} = 75 Ω, See Figure 6		1	5	ns
$t_{sk(lim)}$	Skew limit§	ALS171	R_L = 54 Ω, See Figure 3	C_L = 50 pF,			10	ns
		ALS171A					5	
		ALS171	$R_{L1} = R_{L3}$ = 165 Ω, C_L = 60 pF,	R_{L2} = 75 Ω, See Figure 6			10	
		ALS171A					5	
$t_{t(OD)}$	Differential-output transition time		R_L = 54 Ω, See Figure 3	C_L = 50 pF,	3	8	13	ns
			$R_{L1} = R_{L3}$ = 165 Ω, C_L = 60 pF, See Figure 6	R_{L2} = 75 Ω, V_{TERM} = 5 V,	3	8	13	
t_{PZH}	Output enable time to high level		R_L = 110 Ω,	See Figure 4		30	50	ns
t_{PZL}	Output enable time to low level		R_L = 110 Ω,	See Figure 5		30	50	ns
t_{PHZ}	Output disable time from high level		R_L = 110 Ω,	See Figure 4	3	8	13	ns
t_{PLZ}	Output disable time from low level		R_L = 110 Ω,	See Figure 5	3	8	13	ns
t_{PDE}	Differential-output enable time		$R_{L1} = R_{L3}$ = 165 Ω, C_L = 60 pF,	R_{L2} = 75 Ω, See Figure 7	8	30	45	ns
t_{PDZ}	Differential-output disable time				5	10	45	ns

† All typical values are at V_{CC} = 5 V and T_A = 25°C.
‡ Pulse skew is defined as the $|t_{d(ODH)} - t_{d(ODL)}|$ of each channel.
§ Skew limit is the maximum difference in propagation delay times between any two channels of one device and between any two devices. This parameter is applicable at one V_{CC} and operating temperature within the recommended operating conditions.

SYMBOL EQUIVALENTS

DATA-SHEET PARAMETER	EIA/TIA-422-B	RS-485
V_O	V_{oa}, V_{ob}	V_{oa}, V_{ob}
$\|V_{OD1}\|$	V_o	V_o
$\|V_{OD2}\|$	V_t (R_L = 100 Ω)	V_t (R_L = 54 Ω)
$\|V_{OD3}\|$		V_t (Test Termination Measurement 2)
V_{test}		V_{tst}
$\Delta\|V_{OD}\|$	$\|\|V_t\|-\|\overline{V}_t\|\|$	$\|\|V_t\|-\|\overline{V}_t\|\|$
V_{OC}	$\|V_{os}\|$	$\|V_{os}\|$
$\Delta\|V_{OC}\|$	$\|V_{os} - \overline{V}_{os}\|$	$\|V_{os} - \overline{V}_{os}\|$
I_{OS}	$\|I_{sa}\|$, $\|I_{sb}\|$	
I_O	$\|I_{xa}\|$, $\|I_{xb}\|$	I_{ia}, I_{ib}

RECEIVER SECTION

electrical characteristics over recommended ranges of common-mode input voltage, supply voltage, and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{IT+}	Positive-going input threshold voltage	V_O = 2.7 V,	I_O = –0.4 mA			0.3	V
V_{IT-}	Negative-going input threshold voltage	V_O = 0.5 V,	I_O = 8 mA	–0.3‡			V
V_{hys}	Hysteresis voltage ($V_{IT+} - V_{IT-}$)				60		mV
V_{IK}	Enable-input clamp voltage	I_I = –18 mA				–1.5	V
V_{OH}	High-level output voltage	V_{ID} = 300 mV, See Figure 8	I_{OH} = –400 μA,	2.7			V
V_{OL}	Low-level output voltage	V_{ID} = –300 mV, See Figure 8	I_{OL} = 8 mA,			0.45	V
I_{OZ}	High-impedance-state output current	V_O = 0.4 V to 2.4 V				±20	μA
I_I	Line input current	Other input = 0 V, See Note 4	V_I = 12 V			1	mA
			V_I = –7 V			–0.8	
I_{IH}	High-level enable-input current	V_{IH} = 2.7 V				60	μA
I_{IL}	Low-level enable-input current	V_{IL} = 0.4 V				–300	μA
r_i	Input resistance			12			kΩ
I_{OS}	Short-circuit output current	V_{ID} = 300 mV,	V_O = 0	–15		–85	mA
I_{CC}	Supply current	No load	Outputs enabled		69	90	mA
			Outputs disabled		57	78	

† All typical values are at V_{CC} = 5 V and T_A = 25°C.
‡ The algebraic convention, in which the less positive (more negative) limit is designated minimum, is used in this data sheet for common-mode input voltage and threshold voltage levels only.
NOTE 4: This applies for both power on and off; refer to EIA Standard RS-485 for exact conditions.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature range

PARAMETER			TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	ALS171	V_{ID} = –1.5 V to 1.5 V, C_L = 15 pF, T_A = 25°C, See Figure 9	9		19	ns
		ALS171A		11		16	
t_{PHL}	Propagation delay time, high- to low-level output	ALS171		9		19	ns
		ALS171A		11		16	
$t_{sk(p)}$	Pulse skew§		V_{ID} = –1.5 V to 1.5 V, C_L = 15 pF, See Figure 9		2	5	ns
$t_{sk(lim)}$	Skew limit¶	ALS171				10	ns
		ALS171A				5	
t_{PZH}	Output enable time to high level		C_L = 15 pF, See Figure 10		7	14	ns
t_{PZL}	Output enable time to low level				7	14	ns
t_{PHZ}	Output disable time from high level		C_L = 15 pF, See Figure 10		20	35	ns
t_{PLZ}	Output disable time from low level				8	17	ns

† All typical values are at V_{CC} = 5 V and T_A = 25°C.
§ Pulse skew is defined as the $|t_{PLH} - t_{PHL}|$ of each channel.
¶ Skew limit is the maximum difference in propagation delay times between any two channels of one device and between any two devices. This parameter is applicable at one V_{CC} and operating temperature within the recommended operating conditions.

PARAMETER MEASUREMENT INFORMATION

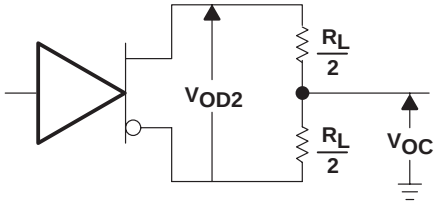


Figure 1. Driver V_{OD} and V_{OC}

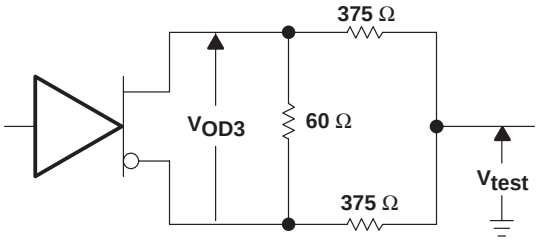
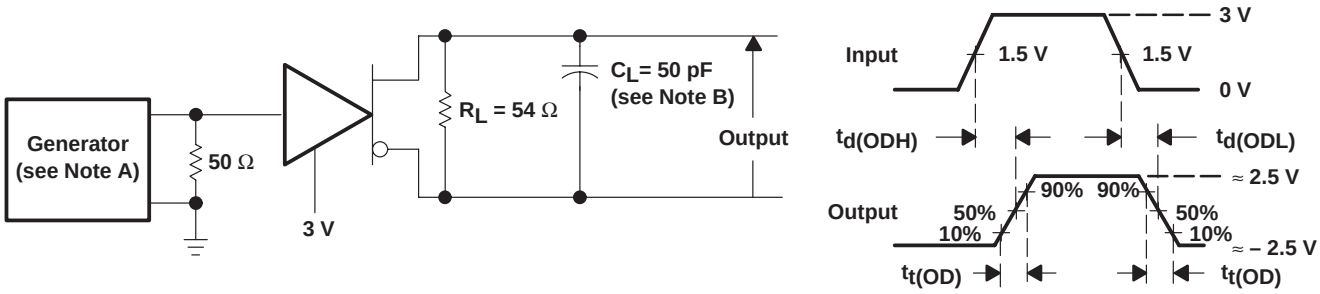


Figure 2. Driver V_{OD3}

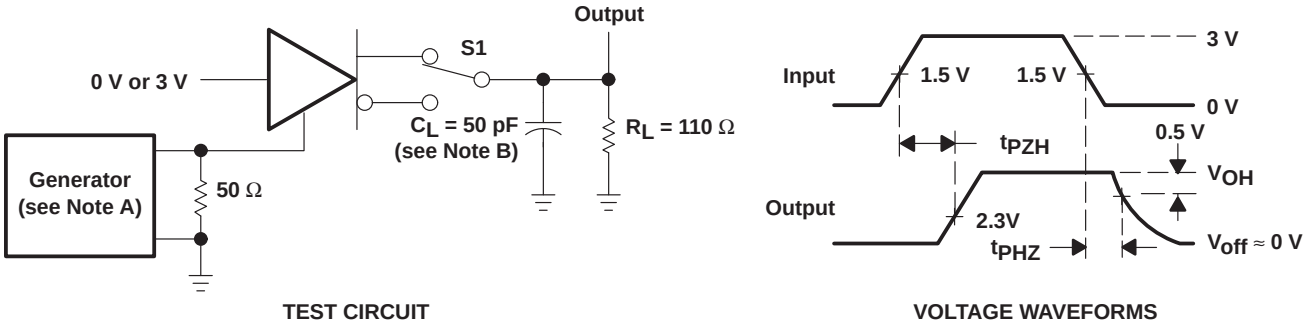


TEST CIRCUIT **VOLTAGE WAVEFORMS**

NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, 50% duty cycle, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.

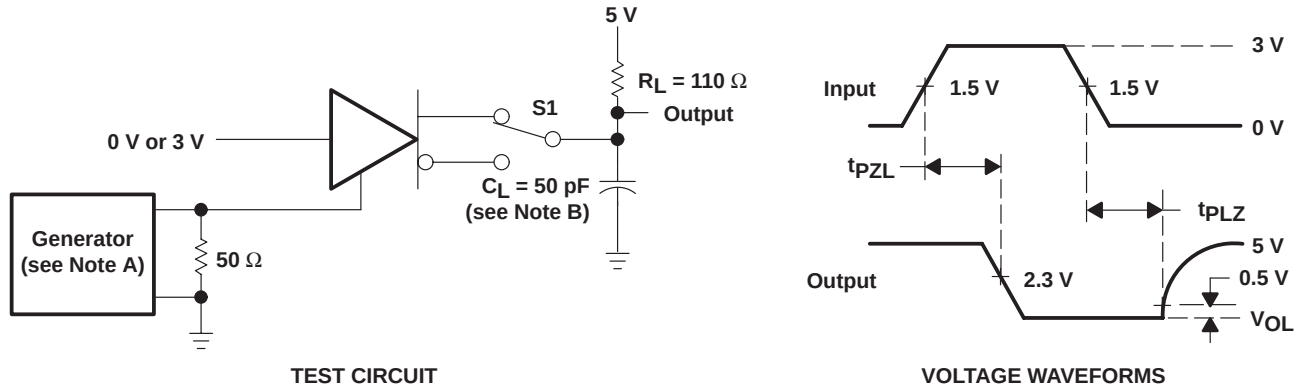
Figure 3. Driver Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, 50% duty cycle, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.

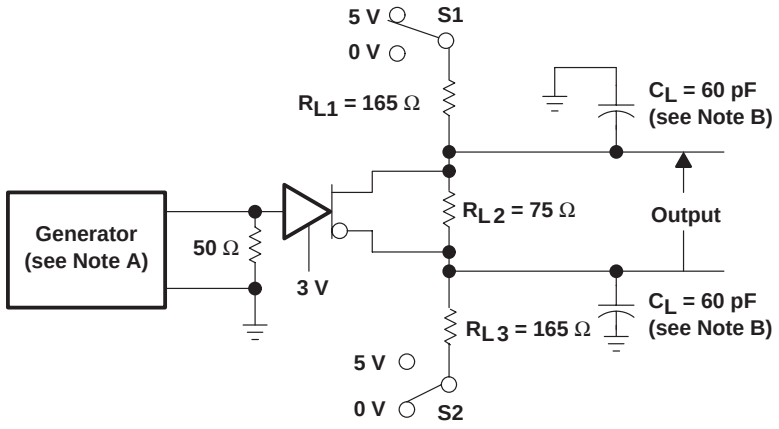
Figure 4. Driver Test Circuit and Voltage Waveforms



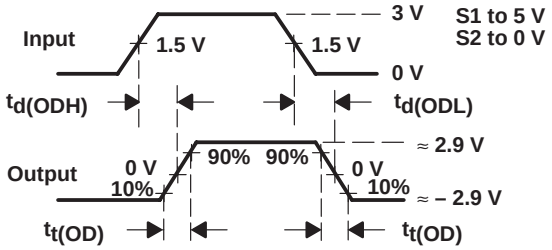
NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, 50% duty cycle, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.

Figure 5. Driver Test Circuit and Voltage Waveforms

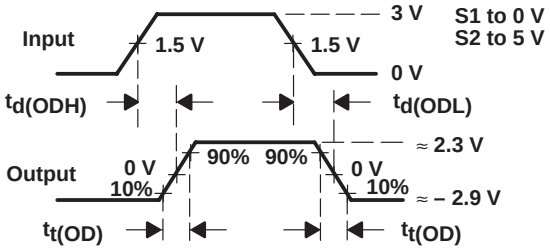
PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT



VOLTAGE WAVEFORMS

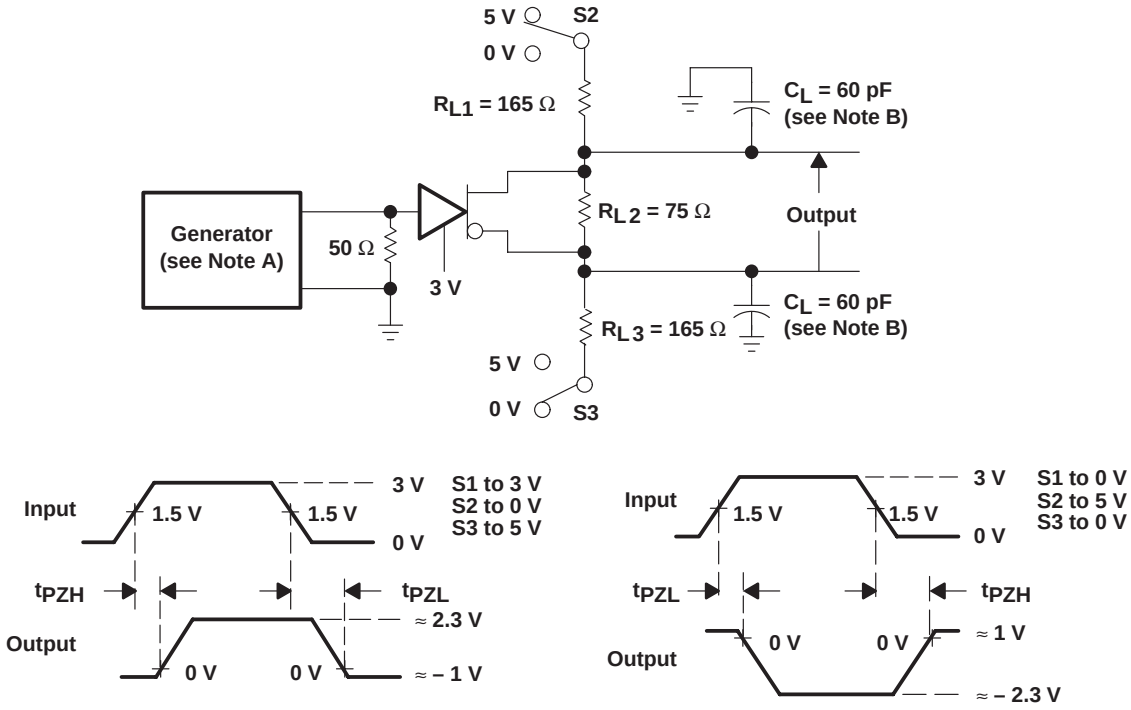


VOLTAGE WAVEFORMS

NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, 50% duty cycle, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.

Figure 6. Driver Test Circuit and Voltage Waveforms With Double-Differential-SCSI Termination for the Load

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, 50% duty cycle, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.

Figure 7. Driver Differential-Enable and Disable Times With a Double-SCSI Termination

PARAMETER MEASUREMENT INFORMATION

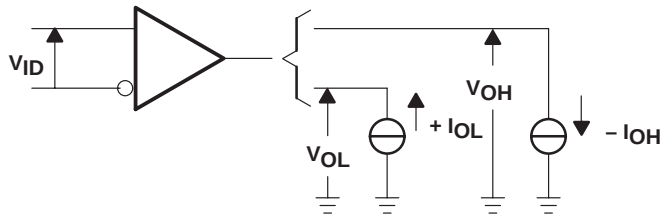
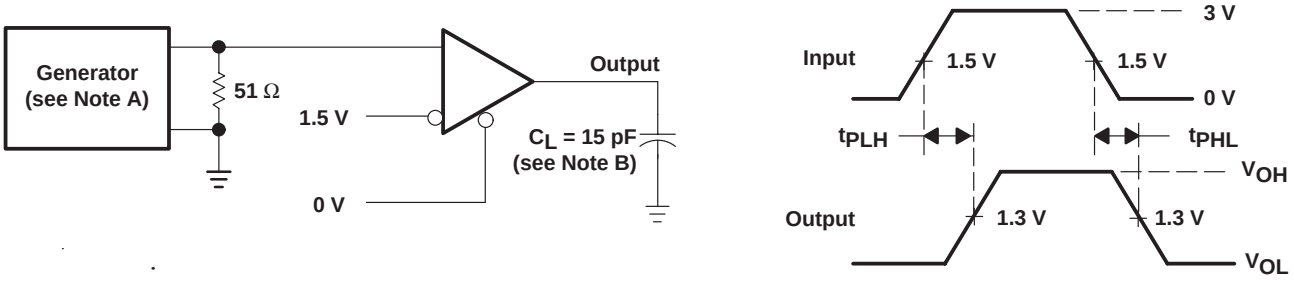


Figure 8. Receiver V_{OH} and V_{OL}

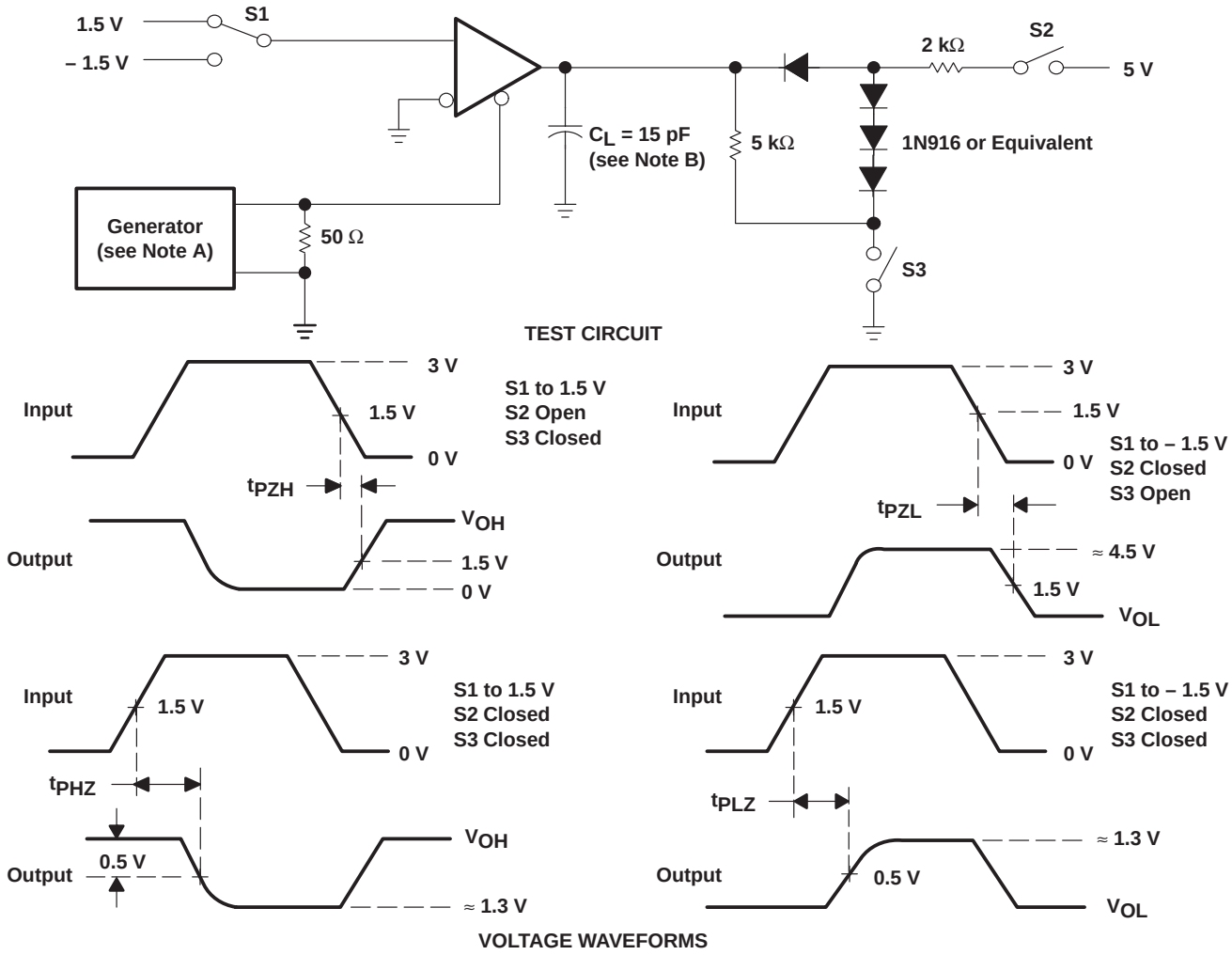


TEST CIRCUIT **VOLTAGE WAVEFORMS**

NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, 50% duty cycle, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.

Figure 9. Receiver Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, 50% duty cycle, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O = 50 Ω.
B. C_L includes probe and jig capacitance.

Figure 10. Receiver Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

DRIVER
HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

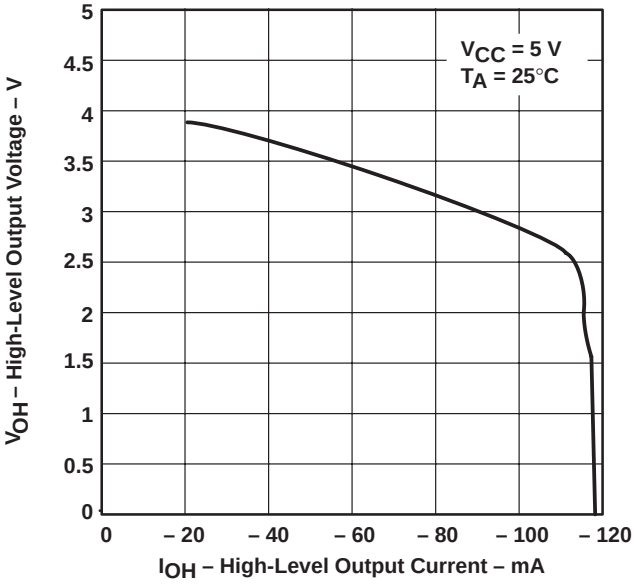


Figure 11

DRIVER
LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

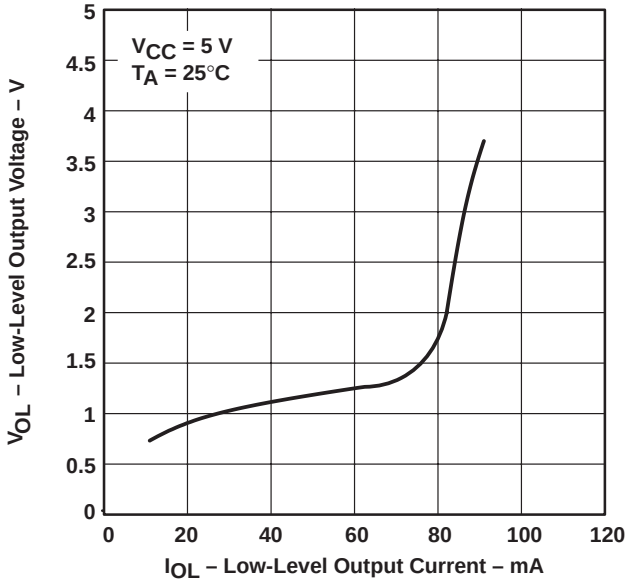


Figure 12

DRIVER
DIFFERENTIAL OUTPUT VOLTAGE
vs
OUTPUT CURRENT

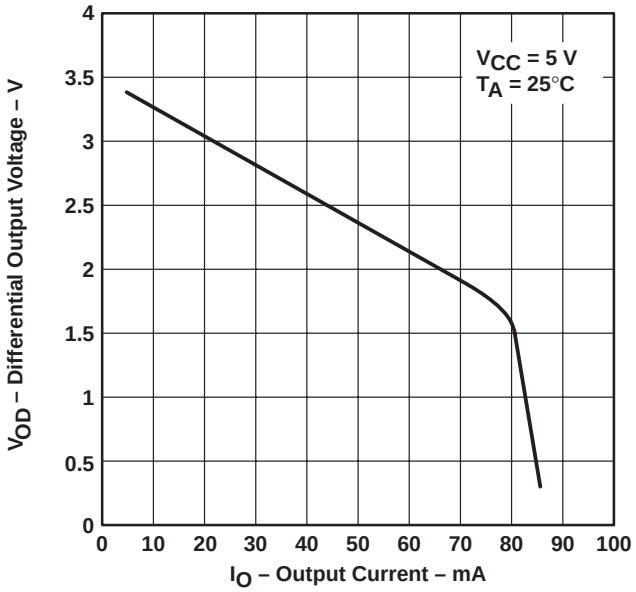


Figure 13

TYPICAL CHARACTERISTICS

RECEIVER
HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

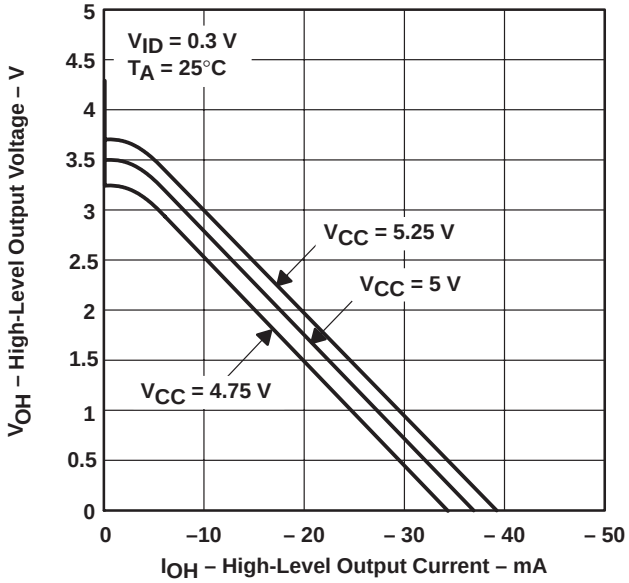


Figure 14

RECEIVER
HIGH-LEVEL OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

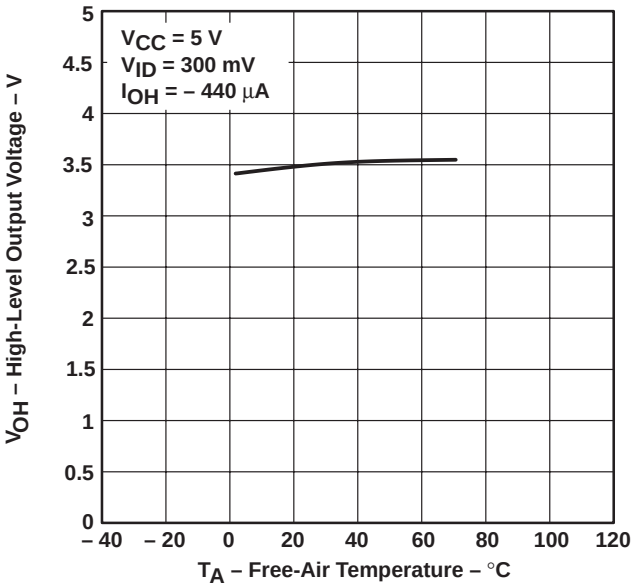


Figure 15

RECEIVER
LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

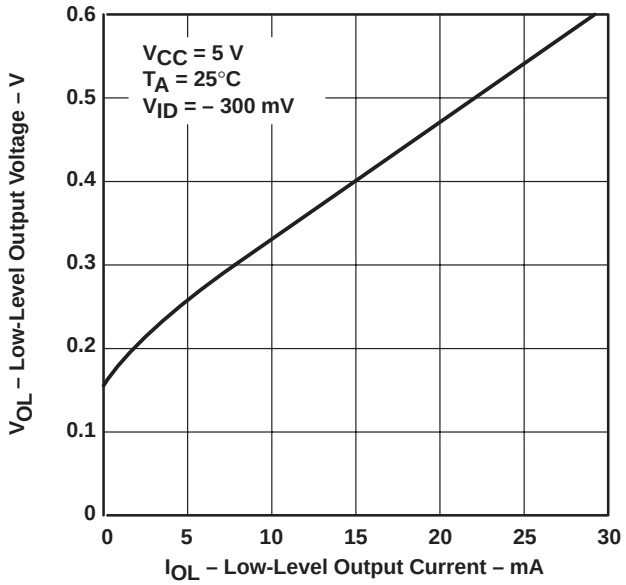


Figure 16

RECEIVER
LOW-LEVEL OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

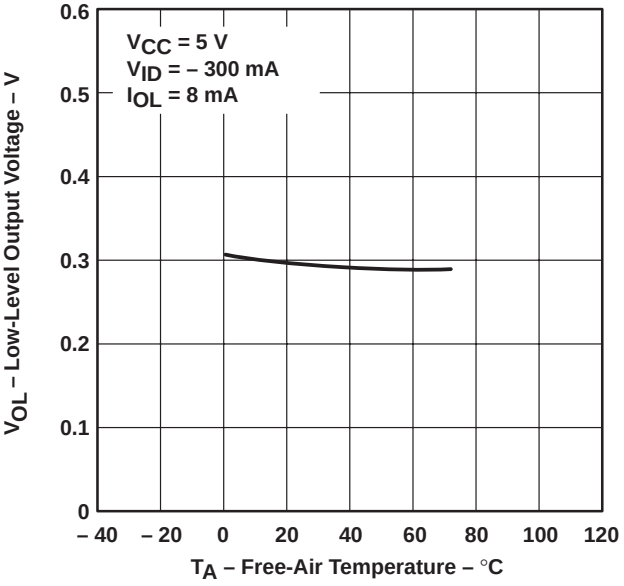


Figure 17

TYPICAL CHARACTERISTICS

RECEIVER
OUTPUT VOLTAGE
vs
ENABLE VOLTAGE

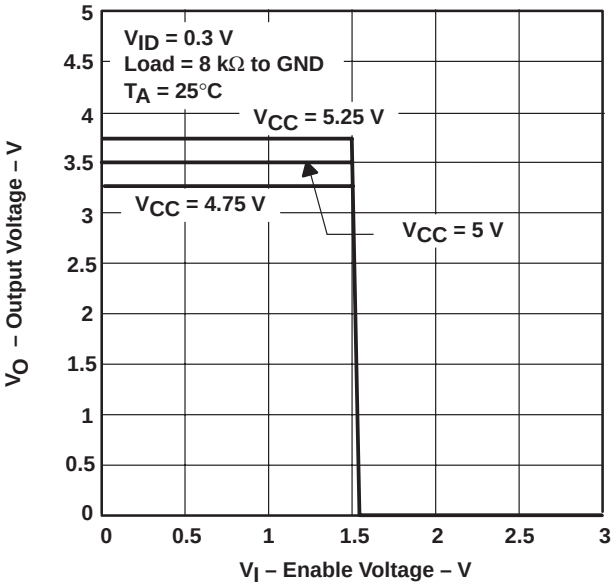


Figure 18

RECEIVER
OUTPUT VOLTAGE
vs
ENABLE VOLTAGE

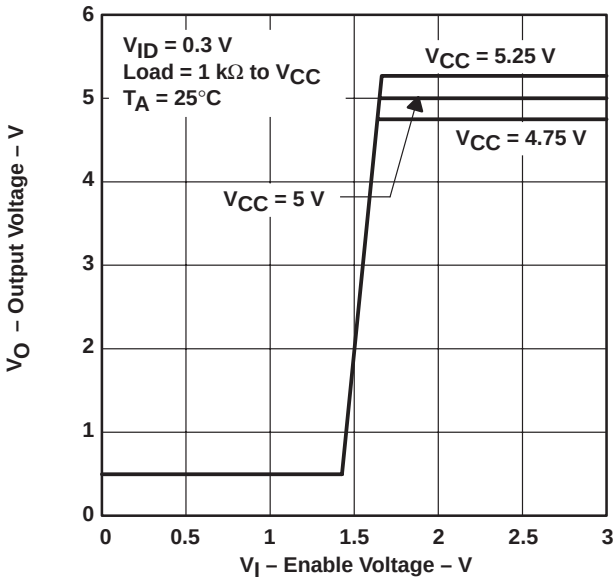
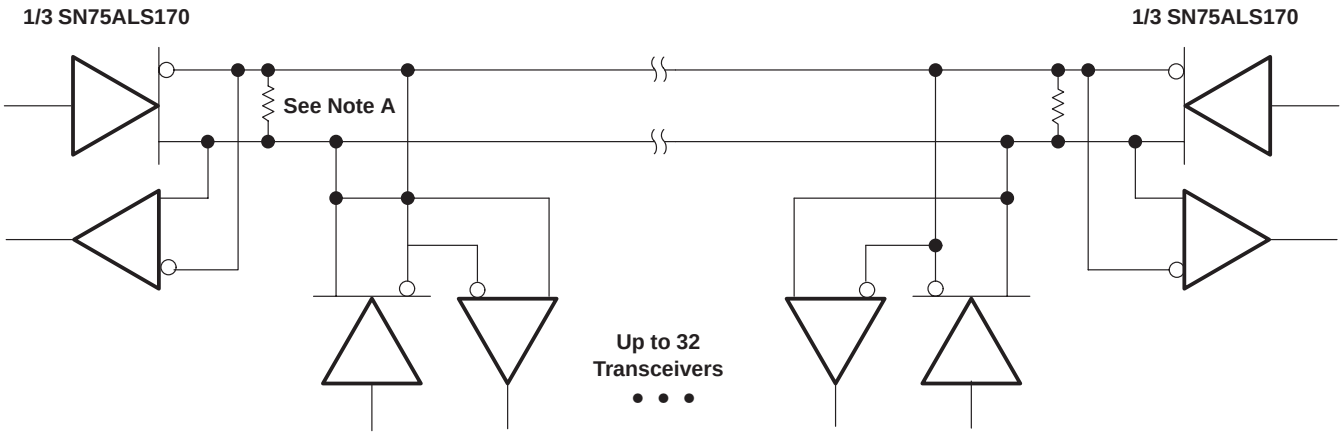


Figure 19

APPLICATION INFORMATION



NOTE A: The line should be terminated at both ends in its characteristic impedance. Stub lengths off the main line should be kept as short as possible.

Figure 20. Typical Application Circuit

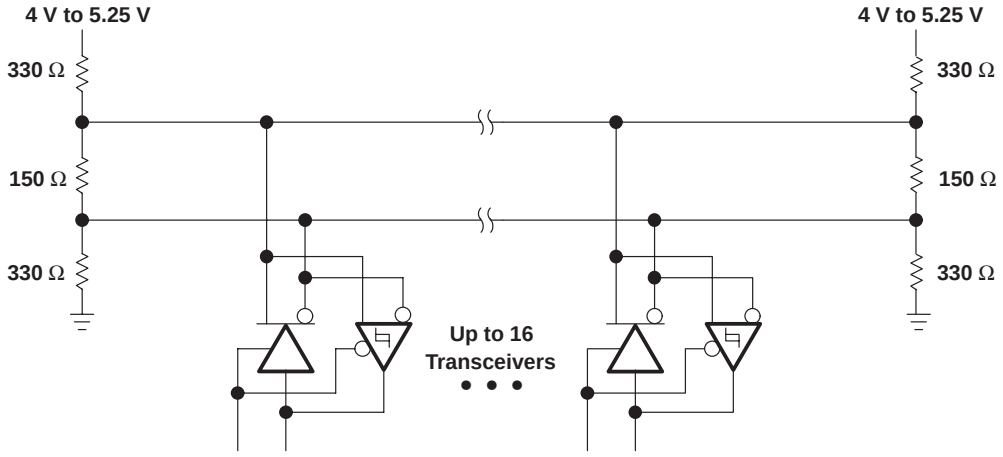


Figure 21. Typical Differential SCSI Application CIrcuit

APPLICATION INFORMATION

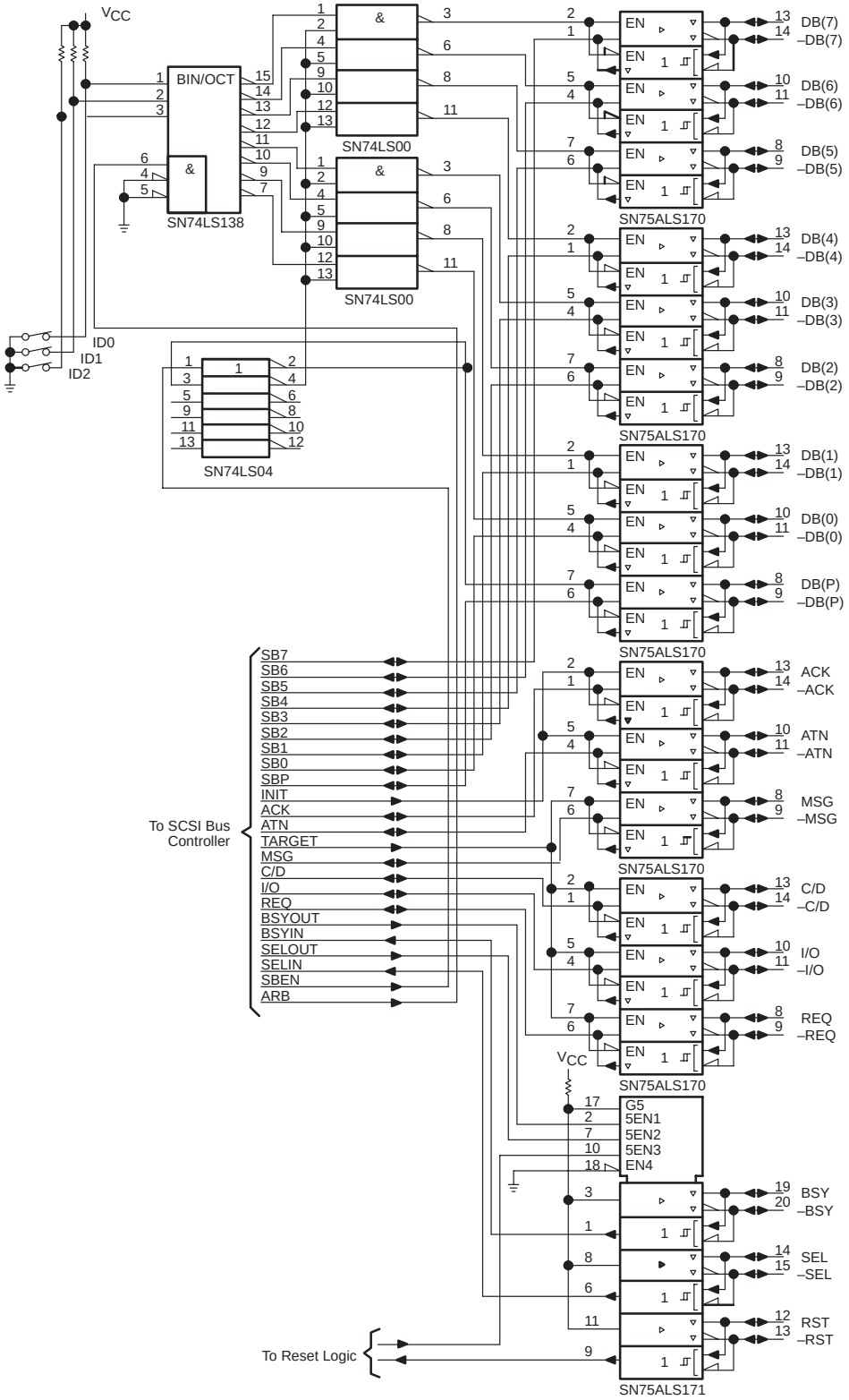


Figure 22. Typical Differential SCSI Bus Interface Implementation

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